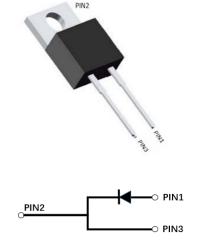


V <sub>RRM</sub>	650V
I <sub>F(135°C)</sub>	5.8A
Q <sub>c</sub>	10nC



#### Features

- Positive temperature coefficient
- Temperature-independent switching
- Maximum working temperature at 175 °C
- Unipolar devices and zero reverse recovery current
- Zero forward recovery current
- Essentially no switching losses
- Reduction of heat sink requirements
- AEC-Q101 qualified
- High-frequency operation
- Reduction of EMI

### **Typical Applications**

Typical applications are in power factor correction(PFC), solar inverter, uninterruptible power supply, motor drives, photovoltaic inverter, electric car and charger.

#### **Mechanical Data**

- Package: TO-220AC Molding compound meets UL 94 V-0 flammability
- rating, RoHS-compliant, halogen-free
- Terminals: Tin plated leads
- Polarity: As marked

### ■Maximum Ratings (Tc=25°C Unless otherwise specified)

PARAMTETER	SYMBOL	UNIT	VALUE
Device marking code			D106504PQG3
Reverse voltage (Repetitive peak) @ T <sub>j</sub> =25°C	V <sub>RRM</sub>	V	650
Reverse voltage (Surge peak) @ T <sub>j</sub> =25°C	V <sub>RSM</sub>	V	650
Reverse voltage (DC) @ T <sub>j</sub> =25°C	V <sub>DC</sub>	V	650
Continuous forward current @ $T_c$ =25°C		A	12
Continuous forward current @ $T_c$ =135°C	I <sub>F</sub>		5.8
Continuous forward current @ $T_c$ =154°C			4
Non-repetitive peak forward surge current @ T <sub>c</sub> =25°C, tp=10ms, Half Sine Wave	I <sub>FSM</sub>	А	40
Power Dissipation@ T <sub>c</sub> =25°C	Р	w	64
Power Dissipation@ T <sub>c</sub> =110°C	P <sub>TOT</sub>	vv	28
i²t Value@ T <sub>c</sub> =25°C ,tp=10ms	∫ i²dt	A <sup>2</sup> S	8
Operating junction and Storage temperature range	T <sub>j</sub> ,T <sub>stg</sub>	°C	-55 to +175

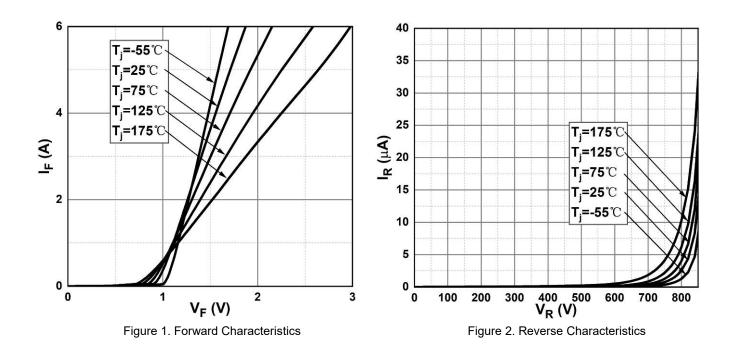
### Electrical Characteristics

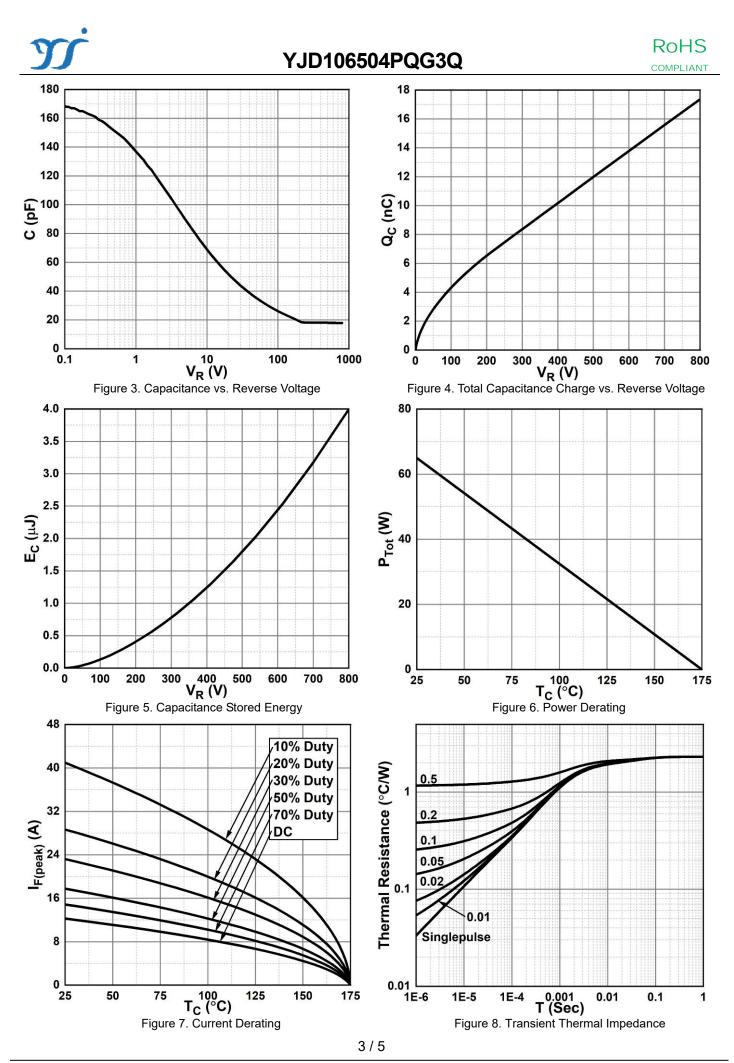
PARAMTETER	SYMBOL	UNIT	TEST CONDITIONS	Тур.	Max.
Forward voltage drop	V <sub>F</sub>	V	I <sub>F</sub> =4A, Tj=25°C	1.56	1.68
			I <sub>F</sub> =4A, Tj=175°C	2.28	-
Reverse leakage current	I <sub>R</sub>	μA	V <sub>R</sub> =650V, T <sub>j</sub> =25°C	0.2	10
			V <sub>R</sub> =650V, T <sub>j</sub> =175°C	1	-
Total capacitive charge	Qc	nC	$V_{\text{R}}\text{=}400\text{V},T_{j}\text{=}25^{\circ}\text{C}$ , $Q_{\text{C}}\text{=}\int_{0}^{V_{\text{R}}}\text{C}(\text{V})\text{dV}$	10	-
Total capacitance	С	pF	V <sub>R</sub> =0V, f=1MHZ	173	-
			V <sub>R</sub> =200V, f=1MHZ	18.3	-
			V <sub>R</sub> =400V, f=1MHZ	18.1	-
Capacitance Stored Energy	Ec	μJ	V <sub>R</sub> =800V	1.25	-

## ■Thermal Characteristics (Ta=25°C Unless otherwise specified)

PARAMETER	SYMBOL	UNIT	VALUE
Thermal resistance	$R_{_{ ext{ hetaJ-C}}}$	°C W	2.31

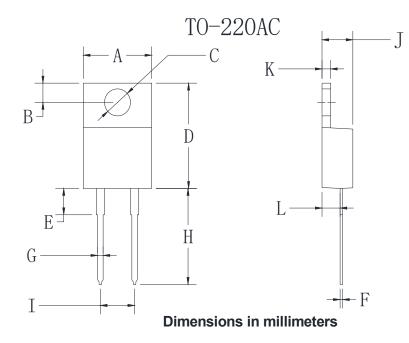
## ■Typical Characteristics







# Outline Dimensions



TO-220AC				
Dim	Min	Max		
А	9.95	10.35		
В	2.55	2.95		
С	3.75	4.05		
D	14.95	15.25		
E	3.75	4.25		
F	0.26	0.5		
G	0.68	0.94		
Н	13.3	13.9		
I	4.86	5.26		
J	4.38	4.78		
К	1.14	1.4		
L	2.37	2.79		

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